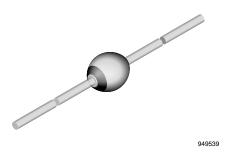


## BYW52, BYW53, BYW54, BYW55, BYW56

**Vishay Semiconductors** 

## **Standard Avalanche Sinterglass Diode**



### **MECHANICAL DATA**

#### Case: SOD-57

**Terminals:** plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

Mounting position: any

Weight: approx. 369 mg

### FEATURES

- Controlled avalanche characteristics
- Glass passivated junction
- Hermetically sealed package
- Low reverse current
- High surge current loading
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **APPLICATIONS**

• Rectification, general purpose

ORDERING INFORMATION (Example)				
DEVICE NAME	ORDERING CODE	TAPED UNITS	MINIMUM ORDER QUANTITY	
BYW56	BYW56-TR	5000 per 10" tape and reel	25 000	
BYW56	BYW56-TAP	5000 per ammopack	25 000	

PARTS TABLE				
PART	TYPE DIFFERENTIATION	PACKAGE		
BYW52	V <sub>R</sub> = 200 V; I <sub>F(AV)</sub> = 2 A	SOD-57		
BYW53	V <sub>R</sub> = 400 V; I <sub>F(AV)</sub> = 2 A	SOD-57		
BYW54	$V_{R} = 600 \text{ V}; \text{ I}_{F(AV)} = 2 \text{ A}$	SOD-57		
BYW55	V <sub>R</sub> = 800 V; I <sub>F(AV)</sub> = 2 A	SOD-57		
BYW56	V <sub>R</sub> = 1000 V; I <sub>F(AV)</sub> = 2 A	SOD-57		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
	See electrical characteristics	BYW52	$V_{R} = V_{RRM}$	200	V	
Reverse voltage = repetitive peak reverse voltage		BYW53	$V_{R} = V_{RRM}$	400	V	
		BYW54	$V_{R} = V_{RRM}$	600	V	
		BYW55	$V_{R} = V_{RRM}$	800	V	
		BYW56	$V_{R} = V_{RRM}$	1000	V	
Peak forward surge current	t <sub>p</sub> = 10 ms, half sine wave		I <sub>FSM</sub>	50	А	
Repetitive peak forward current			I <sub>FRM</sub>	12	А	
Average forward current	φ = 180 °		I <sub>F(AV)</sub>	2	А	
Pulse avalanche peak power	$t_p$ = 20 µs half sine wave, $T_j$ = 175 °C		P <sub>R</sub>	1000	W	
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	l <sub>(BR)R</sub> = 1 Α, Τ <sub>j</sub> = 175 °C		E <sub>R</sub>	20	mJ	
i <sup>2</sup> t-rating			i²t	8	A <sup>2</sup> s	
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C	

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## BYW52, BYW53, BYW54, BYW55, BYW56

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<b>MAXIMUM THERMAL RESISTANCE</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	BOL VALUE		
Junction ambient	Lead length I = 10 mm, $T_L$ = constant	R <sub>thJA</sub>	45	K/W	
Sunction ambient	On PC board with spacing 25 mm	R <sub>thJA</sub>	100	K/W	

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25 \degree C$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 1 A	V <sub>F</sub>	-	0.9	1	V
Reverse current	$V_{R} = V_{RRM}$	I <sub>R</sub>	-	0.1	1	μA
neverse current	$V_{R} = V_{RRM}, T_{j} = 100 \ ^{\circ}C$	I <sub>R</sub>	-	5	10	μA
Breakdown voltage	$I_R = 100 \ \mu A, t_p/T = 0.01, t_p = 0.3 \ ms$	V <sub>(BR)</sub>	-	-	1600	V
Diode capacitance	V <sub>R</sub> = 4 V, f = 1 MHz	CD	-	18	-	pF
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, i_R = 0.25 \text{ A}$	t <sub>rr</sub>	-	-	4	μs
	$I_F = 1 \text{ A}, \text{ dI/dt} = 5 \text{ A/}\mu\text{s}, \text{ V}_R = 50 \text{ V}$	t <sub>rr</sub>	-	-	4	μs
Reverse recovery charge	$I_F = 1 \text{ A}, \text{ dI/dt} = 5 \text{ A/}\mu\text{s}$	Q <sub>rr</sub>	-	-	200	nC

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

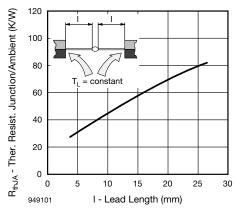


Fig. 1 - Typ. Thermal Resistance vs. Lead Length

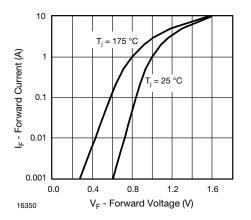


Fig. 2 - Forward Current vs. Forward Voltage

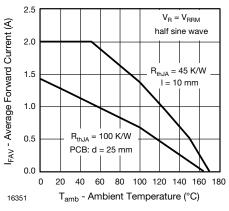


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

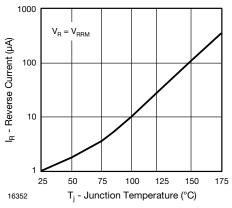


Fig. 4 - Reverse Current vs. Junction Temperature

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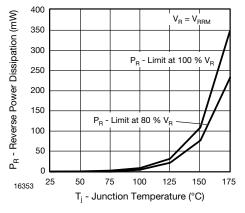


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

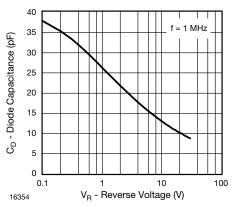


Fig. 6 - Diode Capacitance vs. Reverse Voltage

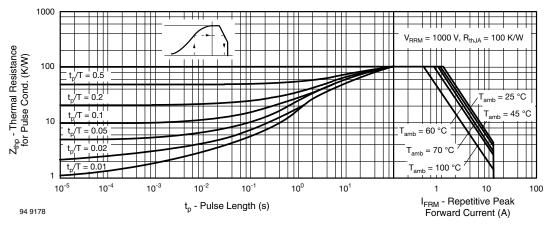
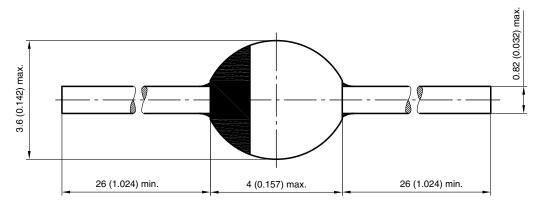


Fig. 7 - Thermal Response

PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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